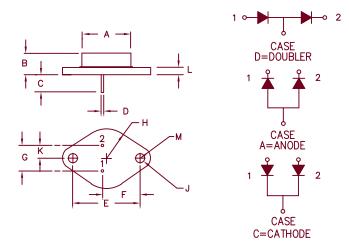
# Schottky Rectifier



Dim	. Inches		Millimete	•	
	Minimum	Maximum	Minimum	Maximum	Notes
Α		.875		22.23	Dia.
В	.250	.450	6.35	11.43	
С	.435		11.05		
D	.038	.043	.97	1.09	Dia.
Ε	1.177	1.197	29.90	30.40	
F	.655	.675	16.64	17.15	
G	.420	.440	10.67	11.18	
Н		.525		13.34	Rad.
J	.151	.161	3.84	4.09	Dia.
K	.205	.225	5.21	5.72	
L		.135		3.43	
М		.188		4.78	Rad.

#### TO-204AA (TO-3)

Microsemi Catalog Number	Industry Part Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage					
SBT3040* SBT3045* SBT3050*	40CDQ035 40CDQ040 40CDQ045	35V 40V 45V 50V	35V 40V 45V 50V					
*ADD D, C, or A								

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low Forward Voltage
- VRRM 40 to 50V
- 30 Amperes
- Reverse Energy Tested

#### Electrical Characteristics Per Leg

Average forward current (standard) F(AV) 30 Amps F(AV) 30 Amps Average forward current (reverse) FSM 600 Amps Maximum surge current IR(OV) 2 Amps Max repetitive peak reverse current VFM .57 Volts Max peak forward voltage Max peak forward voltage Vғм .70 Volts IRM 25 mA Max peak reverse current IRM 1.5 mA Max peak reverse current  $C_{\mathsf{J}}$ VR = 5.0V, TJ = 25°CTypical junction capacitance per lea 1800 pF

 $^{T}C = 148^{\circ}C$ , Square wave,  $^{R}\theta JC = 1.4^{\circ}C/W$  $^{T}C = 132^{\circ}C$ , Square wave,  $^{R}\Theta JC = 2.2^{\circ}C/W$ 8.3 ms, half sine TJ = 175°C o.5 ms, nait sine  $IJ = 1/5^{\circ}C$  f = 1 KHz, 25°C, 1 µsec Square wave IFM = 30A:  $IJ = 175^{\circ}C*$  IFM = 30A:  $IJ = 25^{\circ}C*$  IFM = 30A:  $IJ = 25^{\circ}C*$   $IJ = 25^{\circ}C*$   $IJ = 25^{\circ}C*$   $IJ = 25^{\circ}C*$ 

\*Pulse test: Pulse width 300 jusec, Duty cycle 2%

#### Thermal and Mechanical Characteristics

TSTG Storage temp range -65°C to 175°C ΤJ -65°C to 175°C Operating junction temp range R OJC 1.4°C/W Maximum thermal resistance (standard polarity) Junction to case ROJC Maximum thermal resistance (reverse polarity) 2.2°C/W Junction to case Recs 0.5°C/W Case to sink Typical thermal resistance Weight 1.0 ounces (28 grams) typical



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#### SBT305 SBT304

Figure 1 Typical Forward Characteristics 1000 800 600

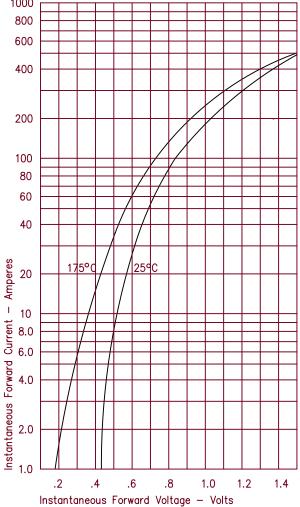
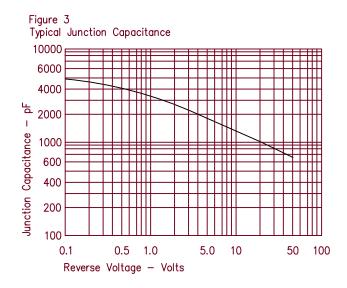
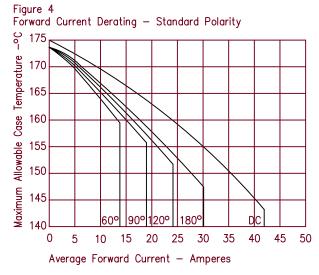
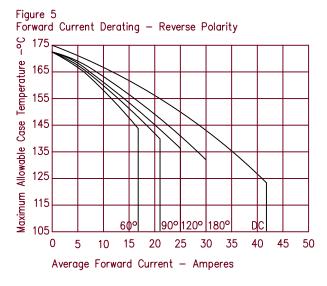


Figure 2 Typical Reverse Characteristics 100 mA 10 75°0 Typical Reverse Current — 1.0 0.1 .01 .001 10 20 30 50 40 Reverse Voltage - Volts







# SBT3040 - SBT3050

Figure 6 Maximum Forward Power Dissipation — Standard Polarity

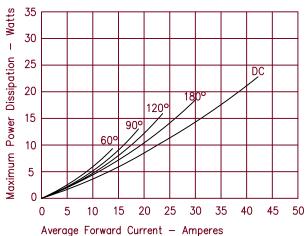
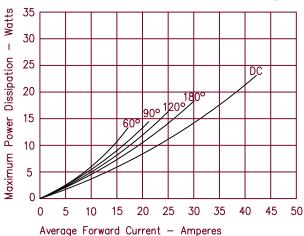


Figure 7 Maximum Forward Power Dissipation — Reverse Polarity



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